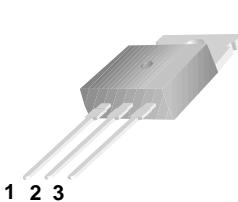
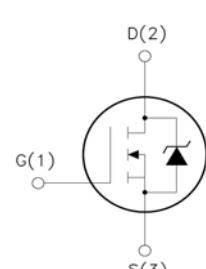


<b>90N10</b>  <b>Features:</b> <ul style="list-style-type: none"> <li><input type="checkbox"/> Low Intrinsic Capacitances.</li> <li><input type="checkbox"/> Excellent Switching Characteristics.</li> <li><input type="checkbox"/> Extended Safe Operating Area.</li> <li><input type="checkbox"/> Unrivalled Gate Charge :Qg=60nC (Typ.).</li> <li><input type="checkbox"/> BVDSS=100V,I<sub>D</sub>=90A</li> <li><input type="checkbox"/> R<sub>Ds(on)</sub> : 0.012Ω (Max) @V<sub>G</sub>=10V</li> <li><input type="checkbox"/> 100% Avalanche Tested</li> </ul>	 <b>TO-220</b>  1.Gate (G) 2.Drain (D) 3.Source (S)
--	--

### Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Maximum	Unit
$V_{DSS}$	Drain-to-Source Voltage	100	V
$V_{GSS}$	Gate-to-Source Voltage	$\pm 25$	V
$I_D^3$	Continuous Drain Current	$T_C=25^\circ\text{C}$	90
		$T_C=100^\circ\text{C}$	51
$I_{DP}^4$	Pulsed Drain Current	$T_C=25^\circ\text{C}$	219
$I_{AS}^5$	Avalanche Current	30	
$E_{AS}^5$	Avalanche energy	225	mJ
PD	Maximum Power Dissipation	$T_C=25^\circ\text{C}$	166
		$T_C=100^\circ\text{C}$	83
$T_J, T_{STG}$	Junction & Storage Temperature Range	-55~175	°C

### Thermal Characteristics

Symbol	Parameter	Typical	Unit
$R_{\theta jc}$	Thermal Resistance-Junction to Case	0.9	°C/W
$R_{\theta ja}$	Thermal Resistance-Junction to Ambient	62.5	

**Electrical Characteristics** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ	Max.	Unit
<b>Static Characteristics</b>						
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}, I_D=250\mu\text{A}$	100	—	—	V
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS}=80\text{V}, V_{GS}=0\text{V}$	—	—	1	uA
		$T_J=125^\circ\text{C}$	—	—	20	
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	2	3	4	V
$I_{GSS}$	Gate Leakage Current	$V_{GS}=\pm 25\text{V}, V_{DS}=0\text{V}$	—	—	$\pm 100$	nA
$R_{DS(on)}^1$	Drain-Source On-Resistance	$V_{GS}=10\text{V}, I_D=50\text{A}$	—	10	12	mΩ
		—	—	—	—	
<b>Diode Characteristics</b>						
$V_{SD}^1$	Diode Forward Voltage	$I_{SD}=50\text{A}, V_{GS}=0\text{V}$	—	—	1.3	V
$I_S^3$	Diode Continuous Forward Current	—	—	90	—	A
$t_{rr}$	Reverse Recovery Time	$I_F=50\text{A},$ $dI/dt=100\text{A}/\mu\text{s}$	—	46	—	nS
$Q_{rr}$	Reverse Recovery Charge		—	86	—	nC
<b>Dynamic Characteristics</b> <sup>2</sup>						
$R_G$	Gate Resistance	$V_{GS}=0\text{V}, V_{DS}=0\text{V},$ Frequency=1MHz	—	1.2	—	Ω
$C_{iss}$	Input Capacitance	$V_{GS}=0\text{V}, V_{DS}=25\text{V}$ Frequency=1MHz	—	3946	—	pF
$C_{oss}$	Output Capacitance		—	454	—	
$C_{rss}$	Reverse Transfer Capacitance		—	295	—	
$t_{d(on)}$	Turn-On Delay Time	$V_{DD}=50\text{V}, I_D=30\text{A},$ $V_{GS}=10\text{V}, R_G=6.8\Omega$	—	15	—	nS
$t_r$	Rise Time		—	108	—	
$t_{d(off)}$	Turn-Off Delay Time		—	51	—	
$t_f$	Fall Time		—	59	—	
<b>Gate Charge Characteristics</b> <sup>2</sup>						
$Q_g$	Total Gate Charge	$V_{DS}=50\text{V}, V_{GS}=10\text{V}$ $I_D=30\text{A}$	—	60	—	nC
$Q_{gs}$	Gate-to-Source Charge		—	13.7	—	
$Q_{gd}$	Gate-to-Drain Charge		—	22.8	—	

Note: 1: Pulse test; pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .

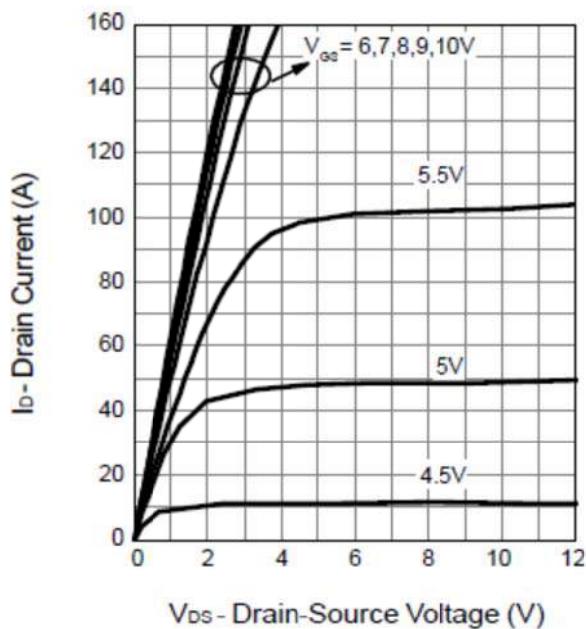
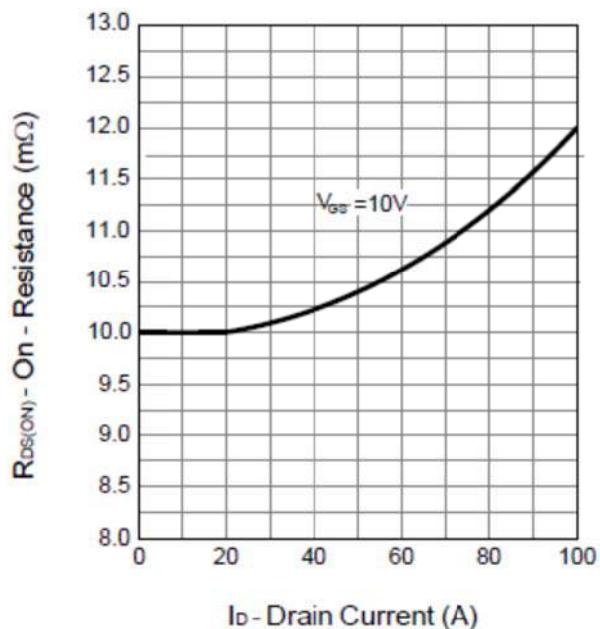
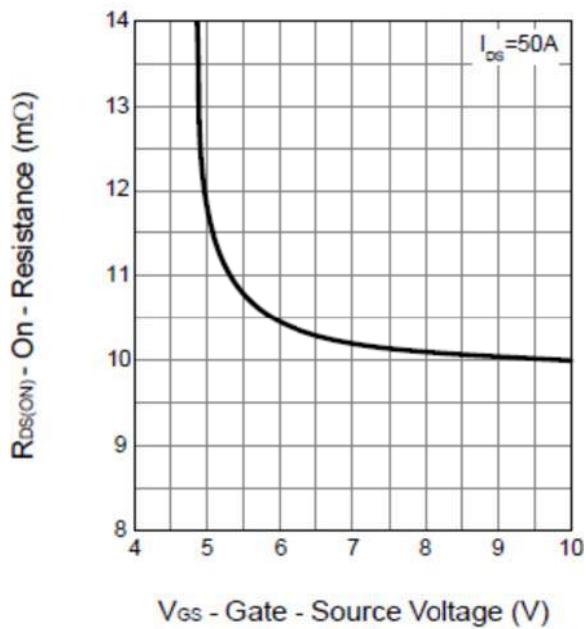
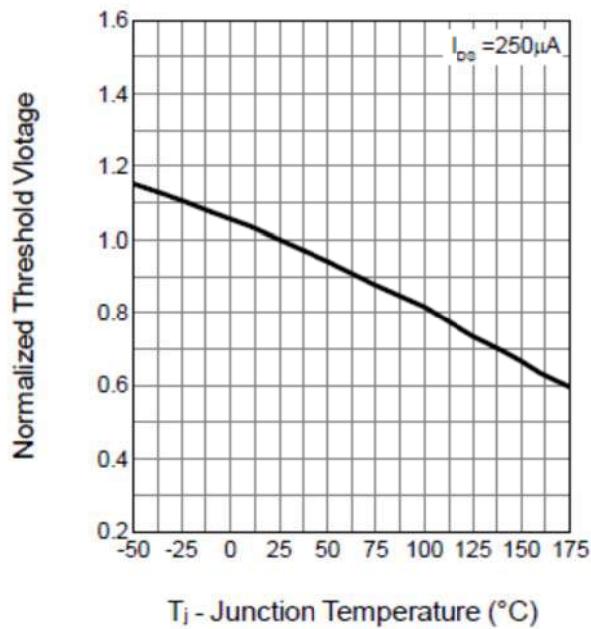
2: Guaranteed by design, not subject to production testing.

3: Package limitation current is 55A.

4: Repetitive rating, pulse width limited by max junction temperature.

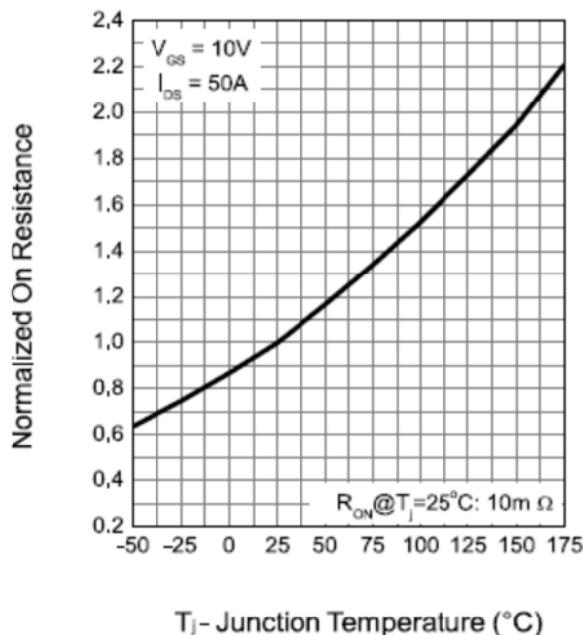
5: Starting  $T_J = 25^\circ\text{C}$ ,  $L = 0.5\text{mH}$ ,  $I_{AS} = 30\text{A}$ .

### Typical Characteristics

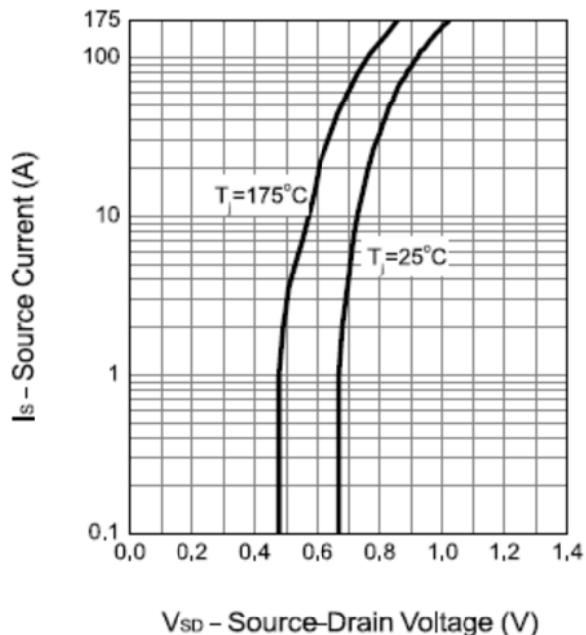
**Output Characteristics**

**Drain-Source On Resistance**

**Drain-Source On Resistance**

**Gate Threshold Voltage**


## Typical Characteristics (Continued)

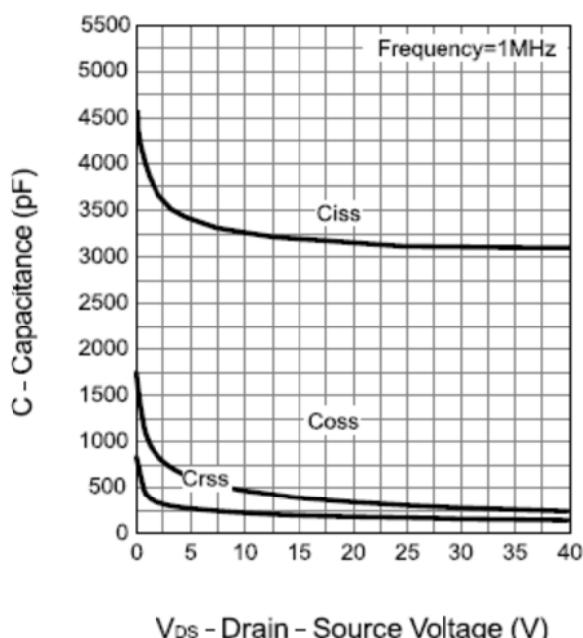
Drain-Source On Resistance



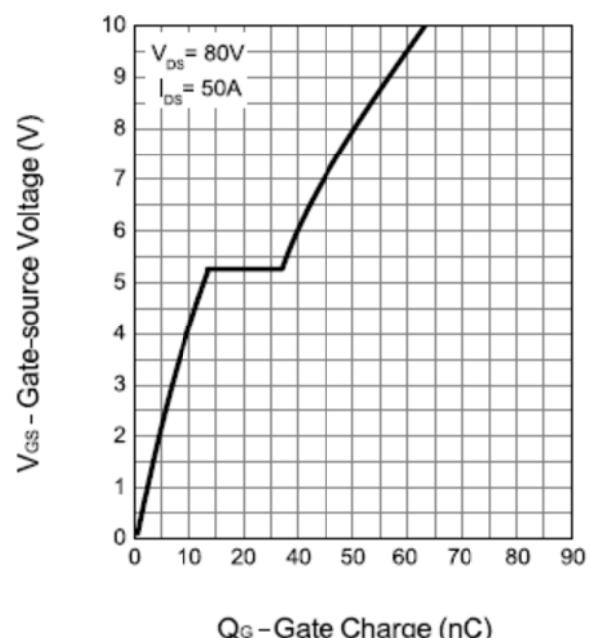
Source-Drain Diode Forward



Capacitance

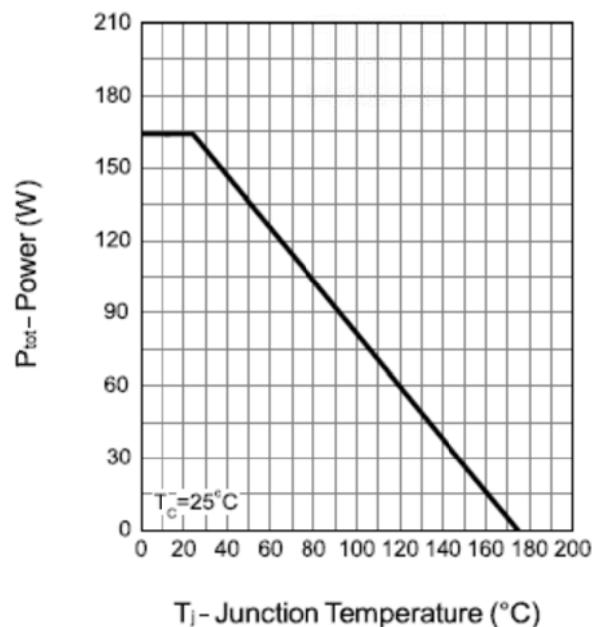


Gate Charge

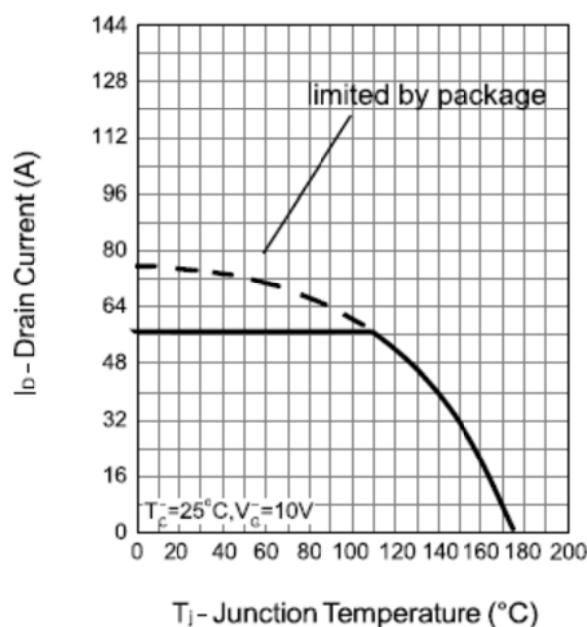


## Typical Characteristics (Continued)

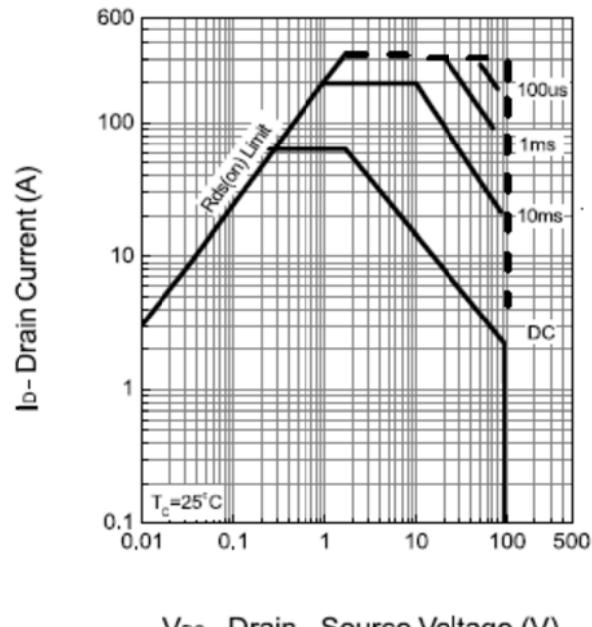
Power Dissipation



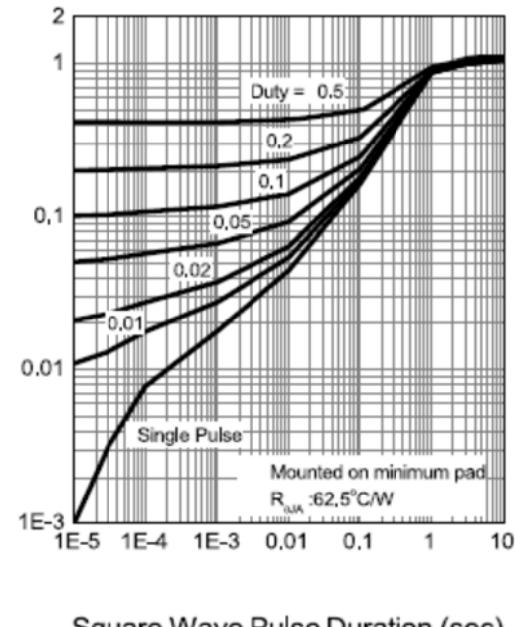
Drain Current



Safe Operation Area



Thermal Transient Impedance

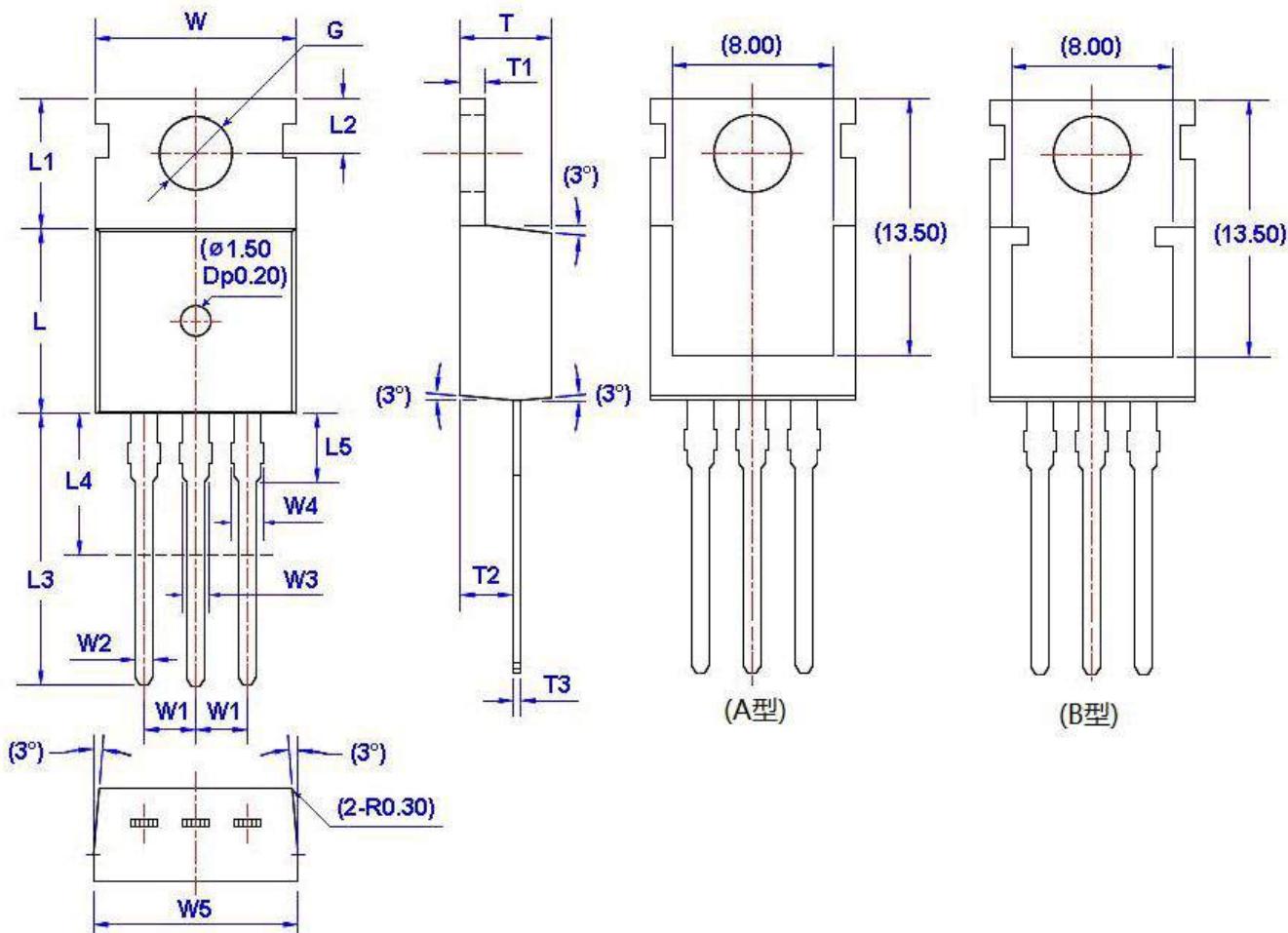

 V<sub>DS</sub> - Drain - Source Voltage (V)

Square Wave Pulse Duration (sec)

## Package Dimension

TO-220

Unit:mm



Symbol	Size		Symbol	Size		Symbol	Size		Symbol	Size	
	Min	Max		Min	Max		Min	Max		Min	Max
W	9.66	10.28	W5	9.80	10.20	L4**	6.20	6.60	T3	0.45	0.60
W1	2.54 (TYP)		L	9.00	9.40	L5	2.79	3.30	G(Φ)	3.50	3.70
W2	0.70	0.95	L1	6.40	6.80	T	4.30	4.70			
W3	1.17	1.37	L2	2.70	2.90	T1	1.15	1.40			
W4*	1.32	1.72	L3	12.70	14.27	T2	2.20	2.60			